



Parameter	Rating	Units
Blocking Voltage	60	V _P
Load Current	150	mA
Max On-Resistance	16	Ω
LED Current to Operate	1	mA

Features

- Designed for use in security systems complying with EN50130-4
- Only 1mA of LED current required to operate
- Small 4-Pin SOP Package
- TTL/CMOS Compatible input
- No Moving Parts
- High Reliability
- Arc-Free With No Snubbing Circuits
- 1500V_{rms} Input/Output Isolation
- No EMI/RFI Generation
- Immune to radiated EM fields
- SMD Pick & Place, Wave Solderable
- Tape & Reel Version Available

Applications

- Security
 - Passive Infrared Detectors (PIR)
 - Data Signalling
 - Sensor Circuitry
- Instrumentation
 - Multiplexers
 - Data Acquisition
 - Electronic Switching
 - I/O Subsystems
 - Meters (Watt-Hour, Water, Gas)
- Medical Equipment—Patient/Equipment Isolation
- Aerospace
- Industrial Controls

Description

The CPC1117N is a miniature 1-Form-B solid state relay in a 4-Pin SOP package that employs optically coupled MOSFET technology to provide 1500V_{rms} of input to output isolation. The efficient MOSFET switches and photovoltaic die use Clare's patented OptoMOS® architecture. The optically coupled output is controlled by the input's highly efficient GaAlAs infrared LED using Clare's state of the art double molded vertical construction packaging to produce the world's smallest relay. The CPC1117N offers board space savings of at least 20% over the competitor's larger 4-Pin SOP relay. It boasts the industries' lowest input current to operate in its class.

Approvals

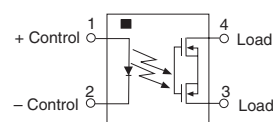
- UL Recognized Component
- EN/IEC 60950-1 compliant

Ordering Information

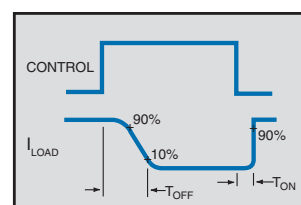
Part #	Description
CPC1117N	4-Pin SOP (100/tube)
CPC1117NTR	4-Pin SOP (2000/reel)

Pin Configuration

CPC1117N Pinout



Switching Characteristics of Normally Closed (Form B) Devices



Absolute Maximum Ratings

Parameter	Ratings	Units
Blocking Voltage	60	V _P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation	70	mW
Total Power Dissipation ¹	400	mW
Isolation Voltage, Input to Output	1500	V _{rms}
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate Linearly 3.33 mW / °C

Electrical absolute maximum ratings are at 25°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics

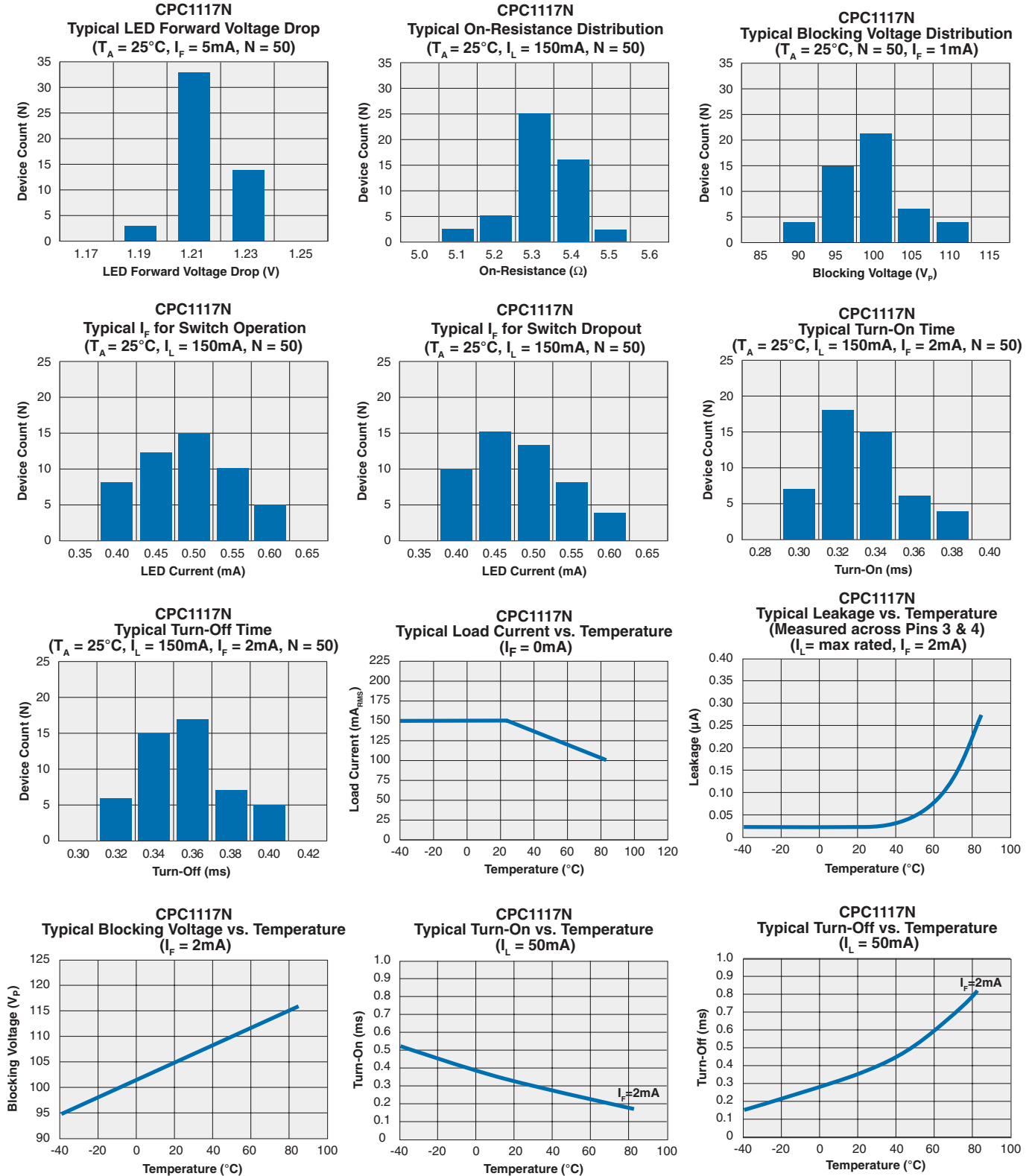
Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics @ 25°C						
Load Current						
Continuous ¹	I _F =0mA	I _L	-	-	150	mA
Peak	t=10ms	I _{LPK}	-	-	350	
On-Resistance ²	I _L =120mA	R _{ON}	-	5	16	Ω
Off-State Leakage Current	V _L =60V, I _F =2mA	I _{LEAK}	-	-	1	μA
Switching Speeds						
Turn-On	I _F =2mA, V _L =10V	T _{ON}	-	-	1	ms
Turn-Off		T _{OFF}	-	-	2	
Output Capacitance	50V; f=1MHz	C _{OUT}	-	25	-	pF
Input Characteristics @ 25°C						
Input Control Current ³	I _L =120mA	I _F	-	-	1	mA
Input Dropout Current	-	I _F	0.3	0.5	-	mA
Input Voltage Drop	I _F =5mA	V _F	0.9	1.2	1.4	V
Reverse Input Current	V _R =5V	I _R	-	-	10	μA
Common Characteristics @ 25°C						
Capacitance Input to Output	-	-	-	1	-	pF

¹ Load current derates linearly from 150mA @ 25°C to 100mA @85°C.

² Measurement taken within 1 second of on time.

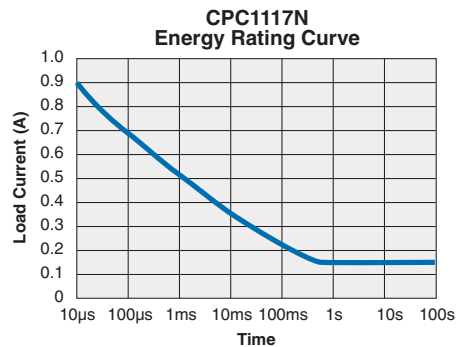
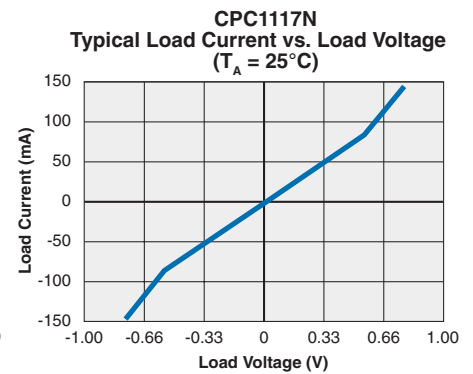
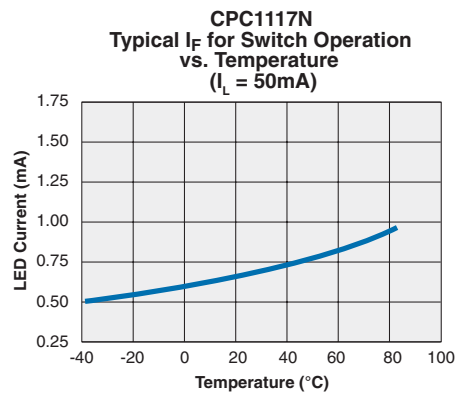
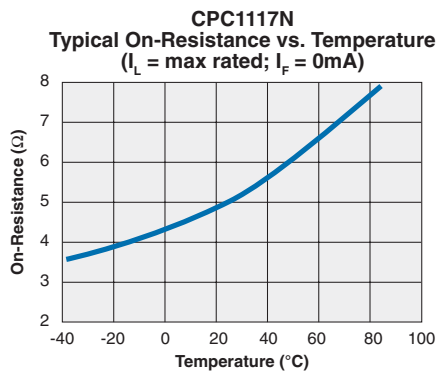
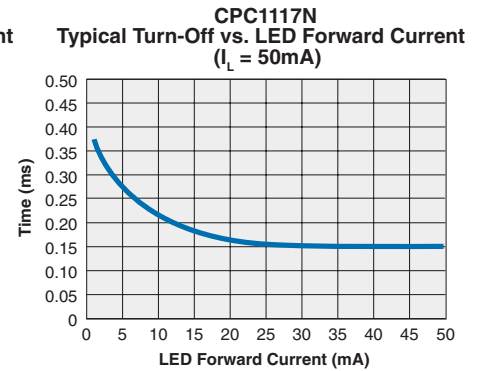
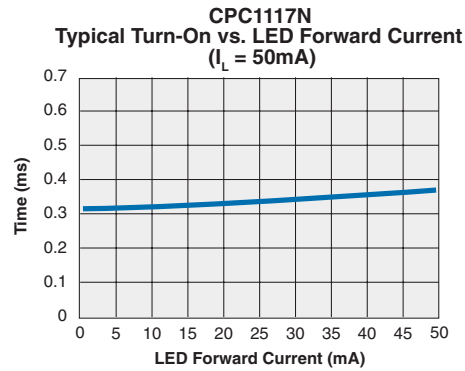
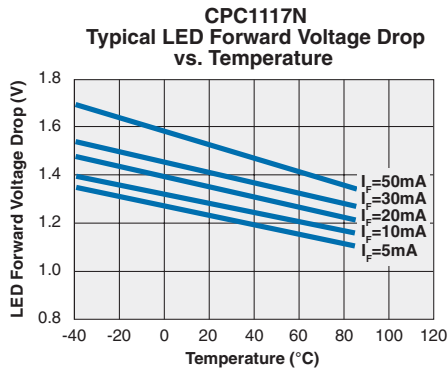
³ For applications requiring high temperature operation (greater than 60°C) an LED drive current of 3mA is recommended.

PERFORMANCE DATA*



*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

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